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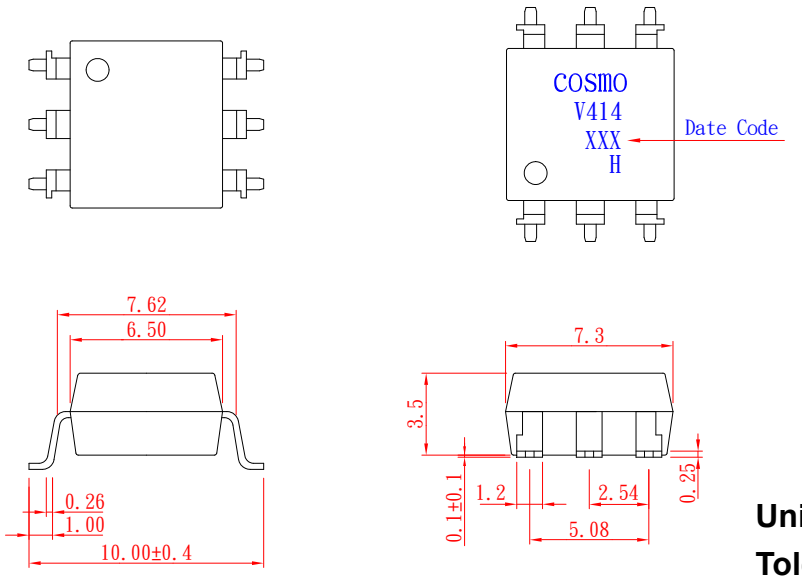
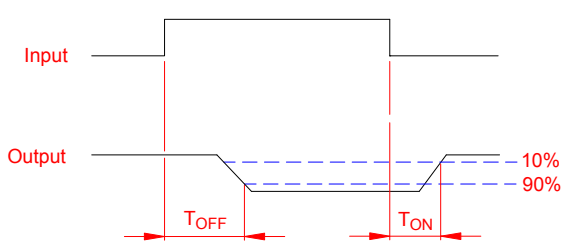
● OUTSIDE DIMENSION：

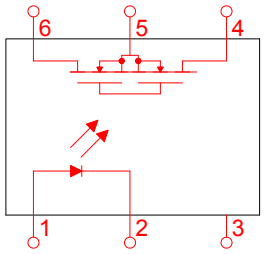


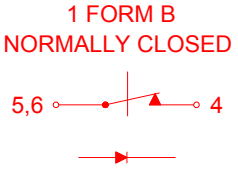
Unit：mm

Tolerance：±0.2mm

● Operate / Reverse time







● Absolute Maximum Ratings

（Ta=25℃）

Emitter（Input）		Detector（Output）	
Reverse Voltage	5.0V	Output Breakdown Voltage	± 400V
Continuous Forward Current	50mA	Continuous Load Current	± 130mA
Peak Forward Current	1A	Power Dissipation	500mW
Power Dissipation	100mW		
Derate Linearly from 25℃	1.3mW/℃		
General Characteristics			
Isolation Test Voltage	5000VACrms	Storage Temperature Range	-40℃ to +125℃
Isolation Resistance Vio=500V，Ta=25℃	≧10^{10}Ω	Operating Temperature Range	-40℃ to +85℃
		Junction Temperature	100℃
Total Power Dissipation	550mW	Soldering Temperature，	
Derate Linearly from 25℃	2.5mW/℃	2mm from case，10 sec	260℃

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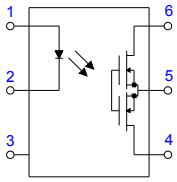
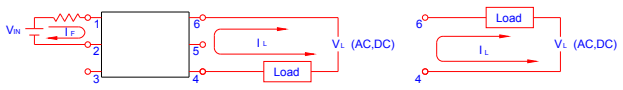
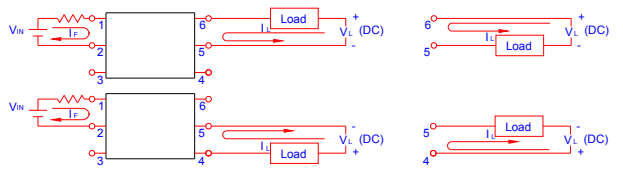
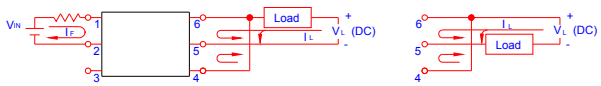
● Electro-optical Characteristics

（Ta=25℃）

Parameter			Symbol	Conditions	Min.	Typ.	Max.	Unit.
Emitter（Input）								
Forward Voltage			V_F	I_F=10mA		1.2	1.5	V
Operation Input Current			IF_{OFF}	V_L=±20V，I_L≦5μA			5.0	mA
Recovery Input Current			IF_{ON}	V_L=±20V，I_L=100mA，t=10ms	0.2			mA
Detector（Output）								
Output Breakdown Voltage			V_B	I_B=50μA，I_F=10mA	400			V
Output Off-State Leakage			IT_{OFF}	V_T=100V，I_F=10mA		0.2	2	μA
I/O Capacitance			C_{ISO}	I_F=0，f=1MHz		6		pF
ON Resistance	Connection	A	R_{ON}	I_L=100mA，I_F=0mA		25	50	Ω
		B				13	25	
		C				7	12.5	
Reverse (ON) Time			T_{ON}	I_F=10mA，V_L=±20V t=10ms，I_L=±100mA		0.6	1.5	ms
Operate (OFF) Time			T_{OFF}			0.3	1.0	ms

● Schematic and Wiring Diagrams

Schematic	Output Configuration	Load	Connection	Wiring Diagrams
	1b	AC/DC	A	
		DC	B	
		DC	C	

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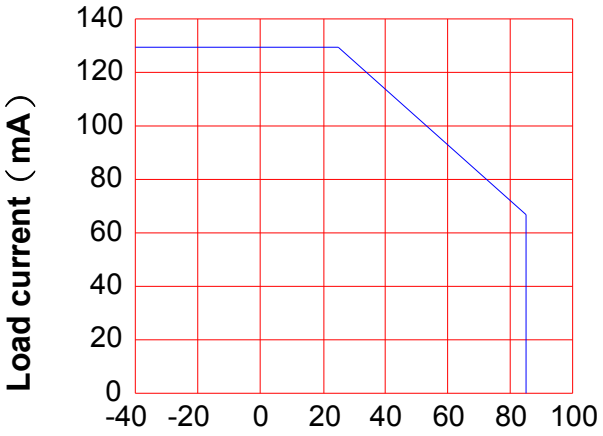
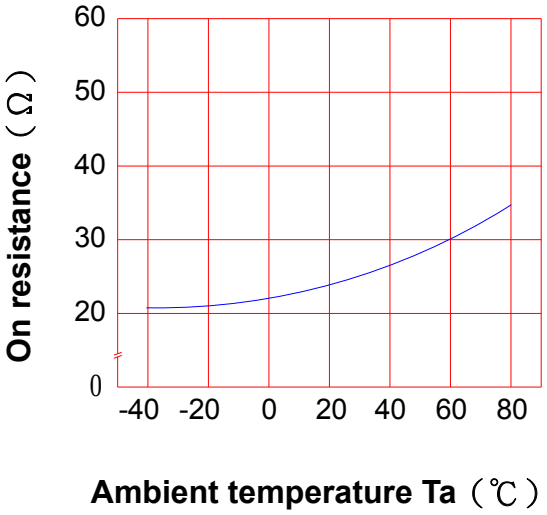
● Data Curve

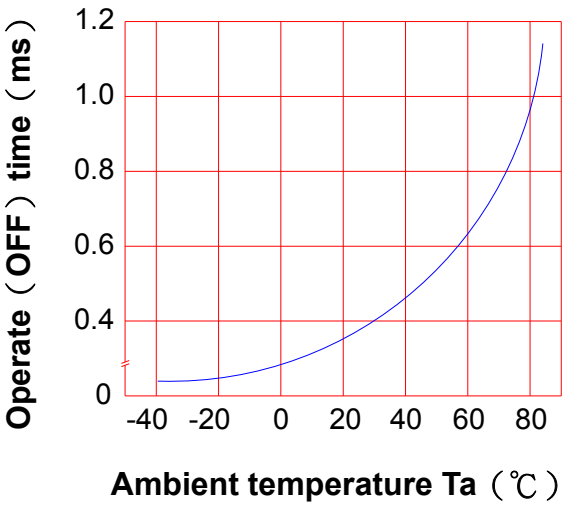
Load current vs. ambient temperature
Allowable ambient Temperature：
-40℃ to +85℃



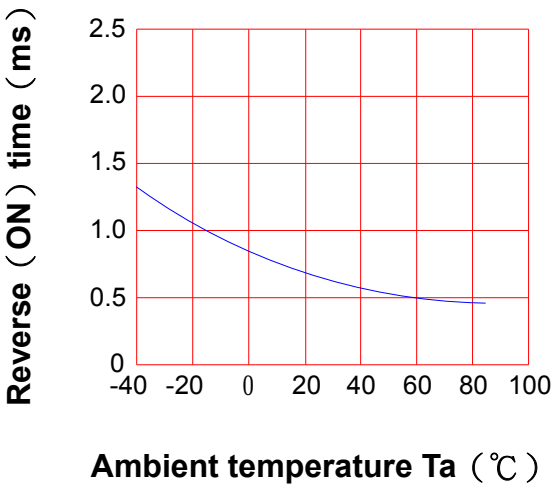
On resistance vs. ambient temperature across terminals 4 and 6 pin
LED current：5mA
Continuous load current：130mA（DC）



Operate（OFF）time vs. ambient temperature
Load voltage 400V（DC）
LED current：5mA
Continuous load current：130mA（DC）



Reverse（ON）time vs. ambient temperature
Load voltage 400V（DC）
LED current：5mA
Continuous load current：130mA（DC）



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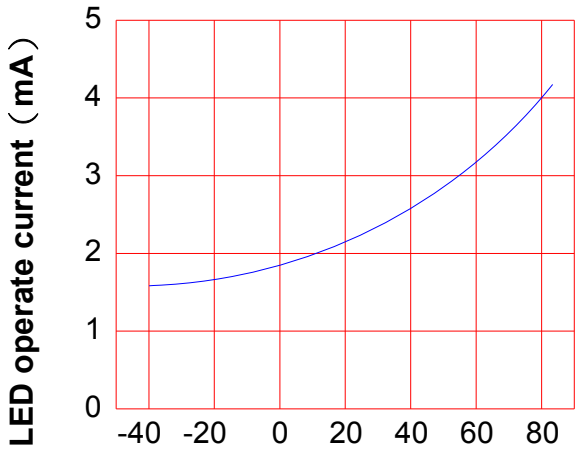
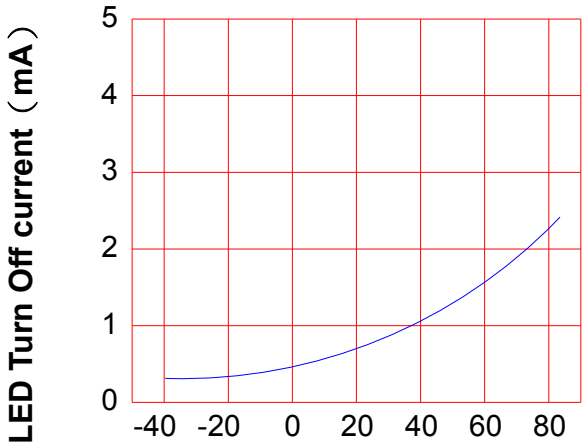
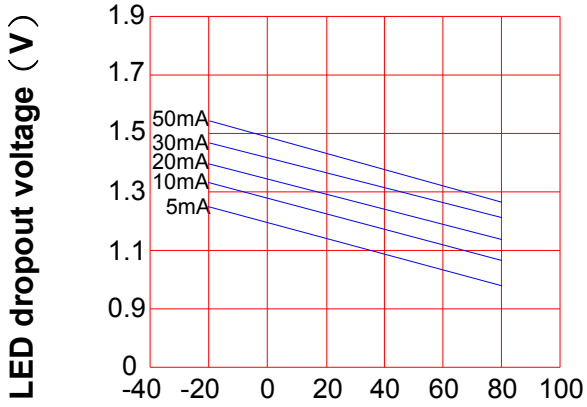
LED operate current vs.
ambient temperature
Load Voltage：400V（DC）
Continuous load current：130mA（DC）



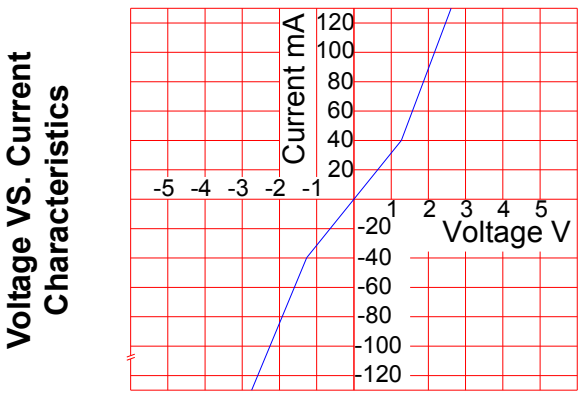
LED Turn Off current vs.
ambient temperature
Load Voltage：400V（DC）
Continuous load current：130mA（DC）



LED dropout voltage vs.
ambient temperature
LED current：5 to 50mA



Voltage vs. current characteristics
of output at MOSFET portion
Measured portion：across terminals
4 and 6 pin
Ambient temperature：25℃



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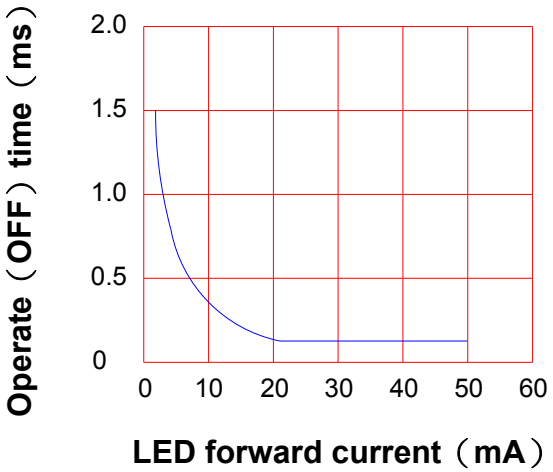
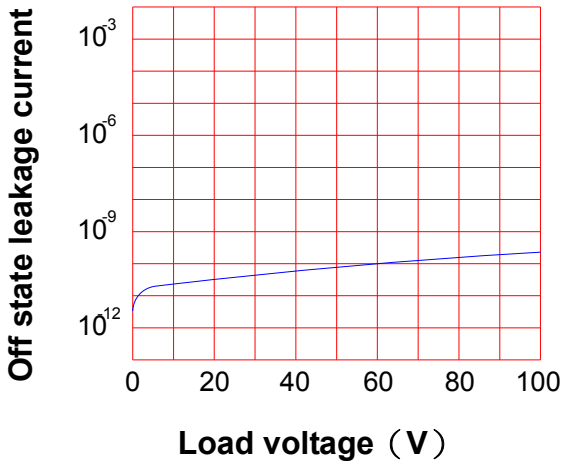
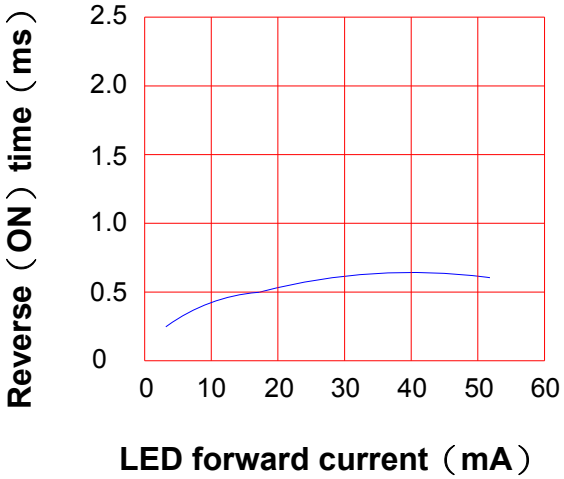
LED forward current vs. Operate（OFF）time
Across terminals 4 and 6 pin
Load voltage：400V（DC）
Continuous load current：130mA（DC）
Ambient temperature：25℃



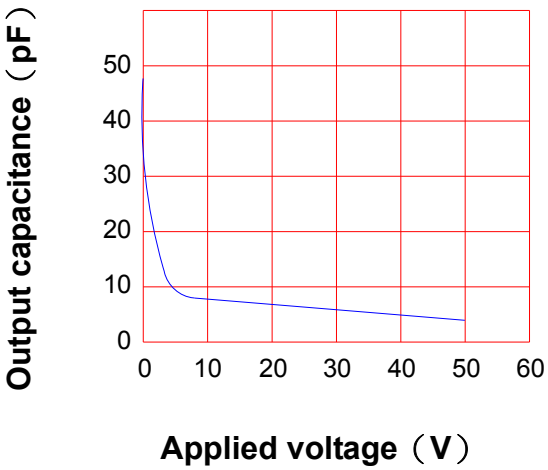
Off state leakage current
Across terminals 4 and 6 pin
Ambient temperature：25℃



LED forward current vs. reverse（ON）time
Across terminals 4 and 6 pin
Load voltage：400V（DC）
Continuous load current：130mA（DC）
Ambient temperature：25℃



Applied voltage vs. output capacitance
Across terminals 4 and 6 pin
Frequency：1MHz
Ambient temperature：25℃



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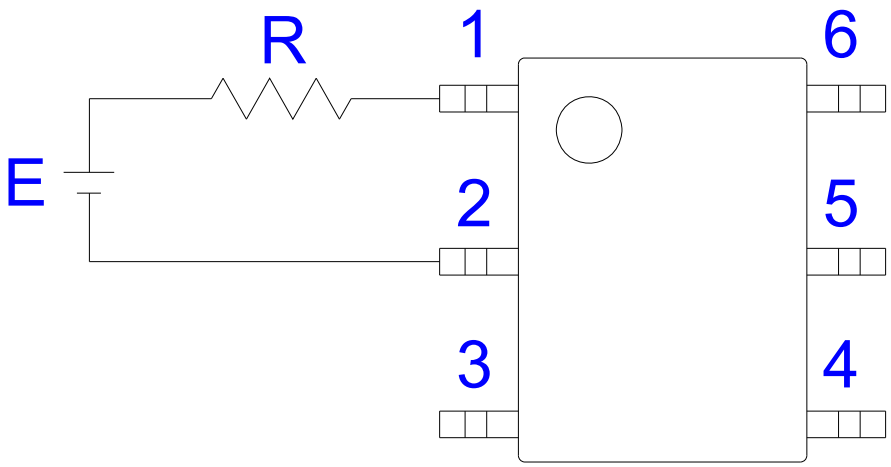
● USING METHODS

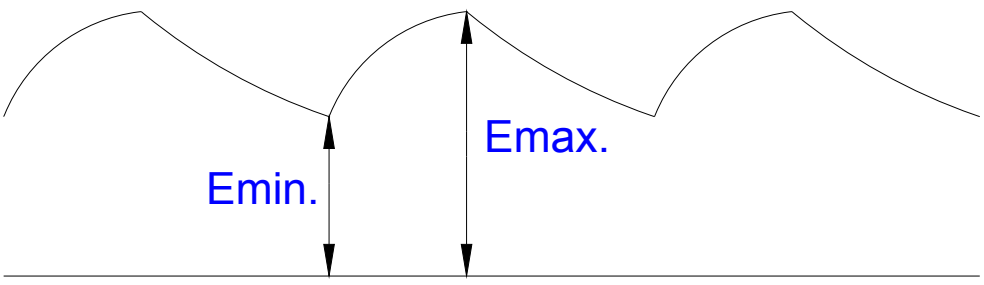
Examples of resistance value to control LED forward current（IF）

SSR-MOSFET OUTPUT **（IF=5mA）**



E	R
3.3V	Approx. 330 Ω
5V	Approx. 640 Ω
12V	Approx. 1.9K Ω
15V	Approx. 2.5K Ω
24V	Approx. 4.1K Ω

（1） LED forward current must be more than 5mA，at E min.
（2） LED forward current must be less than 50mA，at E max.



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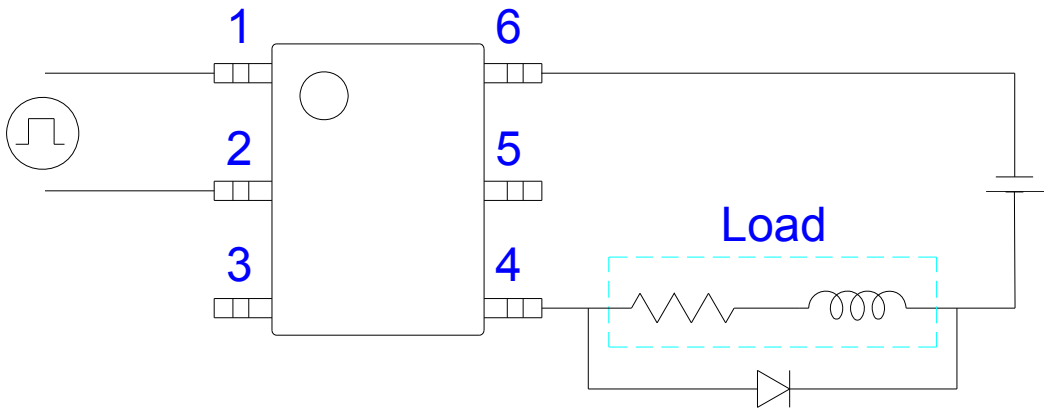
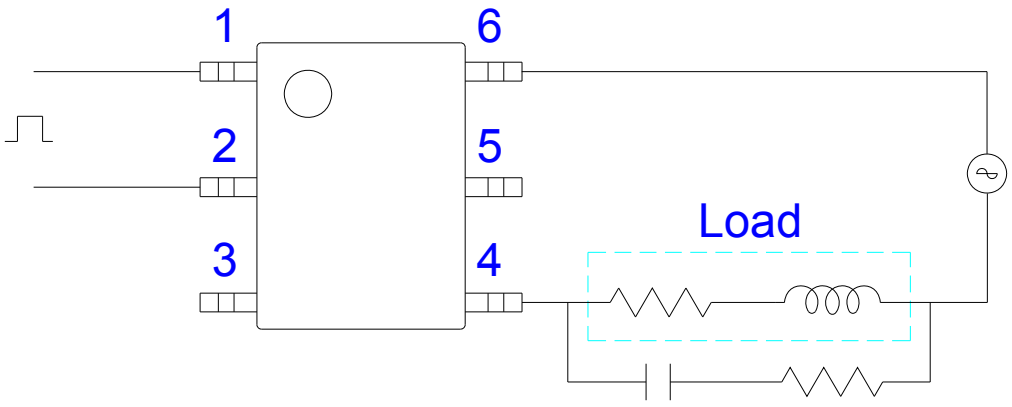
● USING METHODS

Regulate the spike voltage generated on the inductive load as follows：





R-C Snubber